

HI-3182, HI-3183, HI-3184, HI-3185 HI-3186, HI-3187, HI-3188

August 2006

ARINC 429 DIFFERENTIAL LINE DRIVER

GENERAL DESCRIPTION

The HI-3182, HI-3183, HI-3184, HI-3185, HI-3186, HI-3187 and HI-3188 bus interface products are silicon gate CMOS devices designed as a line driver in accordance with the ARINC 429 bus specifications. In addition to being functional upgrades of Holt's HI-8382 & HI-8383 products, they are also alternate sources for the HS-3182 (Intersil/Harris), the RM3182 (Fairchild /Ravtheon) and a variety of similar line driver products from other manufacturers.

Inputs are provided for clocking and synchronization. These signals are AND'd with the DATA inputs to enhance system performance and allow the HI-318X series of products to be used in a variety of applications. Both logic and synchronization inputs feature built-in 2,000V minimum ESD input protection as well as TTL and CMOS compatibility.

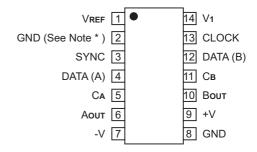
The differential outputs of the HI-318X series of products are programmable to either the high speed or low speed ARINC 429 output rise and fall time specifications through the use of two external capacitors. The output voltage swing is also adjustable by the application of an external voltage to the VREF input. Products with 0, 13 or 37.5 ohm resistors in series with each ARINC output are available. In addition, the HI-3182, HI-3184 and HI-3187 products also have a fuse in series with each output.

The HI-318X series of line drivers are intended for use where logic signals must be converted to ARINC 429 levels such as when using an ASIC, the HI-3282/HI-8282A ARINC 429 Serial Transmitter/Dual Receiver, the HI-6010 ARINC 429 Transmitter/Receiver or the HI-8783 ARINC Interface Device. Holt products are readily available for both industrial and military applications. Please contact the Holt Sales Department for additional information.

FEATURES

- Low power CMOS
- TTL and CMOS compatible inputs
- Programmable output voltage swing
- Adjustable ARINC rise and fall times
- Plastic 14 & 16-pin thermally enhanced SOIC packages available
- · Pin-for-Pin alternative for Intersil/Fairchild applications
- Operates at data rates up to 100 Kbits
- Overvoltage protection
- · Industrial and Military temperature ranges

PIN CONFIGURATION (Top View)



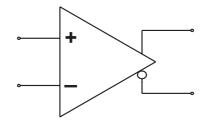
HI-3184PS. HI-3185PS. HI-3186PS & HI-3187PS

14 - PIN PLASTIC SMALL OUTLINE (ESOIC)** NB

Notes: * Pin 2 may be left floating ** Thermally Enhanced SOIC Package

(See Page 6 for additional package pin configurations)

FUNCTION



ARINC 429 DIFFERENTIAL LINE DRIVER

TRUTH TABLE

SYNC	CLOCK	DATA(A)	DATA(B)	AOUT	BOUT	COMMENTS
Х	L	Х	Х	0V	0V	NULL
L	Х	Х	Х	0V	0V	NULL
н	Н	L	L	0V	0V	NULL
н	Н	L	Н	-Vref	+VREF	LOW
н	Н	Н	L	+VREF	-Vref	HIGH
н	Н	Н	Н	0V	0V	NULL

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FUNCTIONAL DESCRIPTION

The SYNC and CLOCK inputs establish data synchronization utilizing two AND gates, one for each data input (figure 2). Each logic input, including the power enable (STROBE) input, are TTL/CMOS compatible.

Figure 1 illustrates a typical ARINC 429 bus application. Three power supplies are necessary to operate the HI-3182; typically +15V, -15V and +5V. The chip also works with \pm 12V supplies. The +5V supply can also provide a reference voltage that determines the output voltage swing. The differential output voltage swing will equal 2VREF. If a value of VREF other than +5V is needed, a separate +5V power supply is required for pin V1.

With the DATA (A) input at a logic high and DATA (B) input at a logic low, AOUT will switch to the +VREF rail and BOUT will switch to the -VREF rail (ARINC HIGH state). With both data input signals at a logic low state, the outputs will both switch to 0V (ARINC NULL state).

The driver output impedance, Rout, is nominally 75, 26 or 0 ohms depending on the option chosen. The rise and fall times of the outputs can be calibrated through the selection of two external capacitor values that are connected to the CA and CB input pins. Typical values for high-speed operation (100KBPS) are CA = CB = 75pF and for low-speed operation (12.5 to 14KBPS) CA = CB = 500pF.

The CA and CB pins swing between +5V and ground allowing the switching of capacitor values with an external single-supply analog switch.

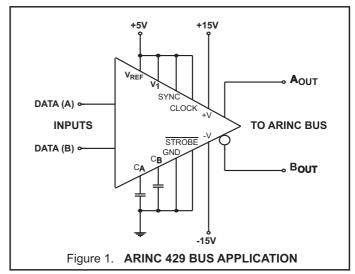
The ARINC outputs can be put in a tri-state mode by applying a logic high to the STROBE input pin. If this feature is not being used, the pin should be tied to ground. The STROBE function is not available in the 14 & 16-pin SOIC package configurations where the pin is internally connected to ground.

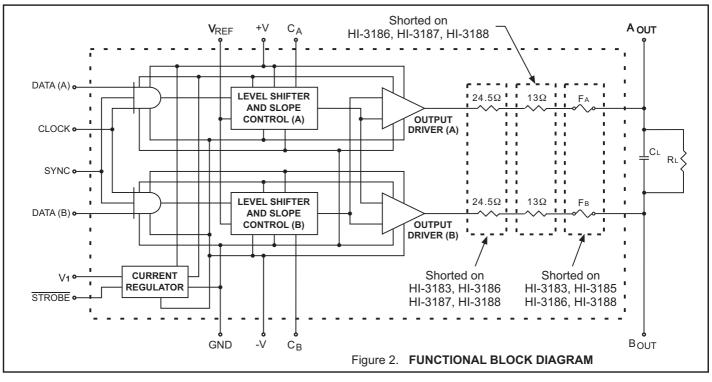
The ARINC outputs of the HI-3182, HI-3184 and HI-3187 are protected by internal fuses capable of sinking between 800 - 900 mA for short periods of time (125μ s).

The Vref pin has an internal pull-up resistor to V+, allowing the use of a simple external zener diode to set the reference voltage.

POWER SUPPLY SEQUENCING

The power supplies should be controlled to prevent large currents during supply turn-on and turn-off. The recommended sequence is +V followed by V1, always ensuring that +V is the most positive supply. The -V supply is not critical and can be asserted at any time.





PIN DESCRIPTIONS

SYMBOL	FUNCTION	DESCRIPTION
VREF	ANALOG	Ref. voltage used to determine output voltage swing. Pin sources current to allow use of a zener reference.
STROBE	INPUT	A logic high tri-states the ARINC outputs. Not available in the 14-pin SOIC package (tied to GND internally).
SYNC	INPUT	Synchronizes data inputs
DATA (A)	INPUT	Data input terminal A
СА	INPUT	Connection for DATA (A) slew-rate capacitor
Аоит	OUTPUT	ARINC output terminal A
-V	POWER	-12V to -15V
GND	POWER	0.0V
+V	POWER	+12V to +15V
Воит	OUTPUT	ARINC output terminal B
Св	INPUT	Connection for DATA (B) slew-rate capacitor
DATA (B)	INPUT	Data input terminal B
CLOCK	INPUT	Synchronizes data inputs
V1	POWER	+5V ±5%

ABSOLUTE MAXIMUM RATINGS

All Voltages referenced to GND, TA = Operating Temperature Range (unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	OPERATING RANGE	MAXIMUM	UNIT
Differential Voltage	Vdif	Voltage between +V and -V terminals		40	V
Supply Voltage	+V -V V1		+10.8 to +16.5 -10.8 to -16.5 +5 ±5%	+7	V V V
Voltage Reference	VREF	For ARINC 429 For Applications other than ARINC	+5 ±5% 1.5 to 6	6 6	V V
Input Voltage Range	Vin			<u>></u> GND -0.3 <u><</u> V1 +0.3	V V
Output Short-Circuit Duration		See Note: 1			
Output Overvoltage Protection		See Note: 2			
Operating Temperature Range	TA	High-temp & Military Industrial	-55 to +125 -40 to +85		ů ů
Storage Temperature Range	Тѕтс	Ceramic & Plastic	-65 to +150		°C
Lead Temperature		Soldering, 10 seconds		+275	°C
Junction Temperature	TJ			+175	°C

The fuses used for Output Overvoltage Protection may be blown by the presence of a voltage at either output that is greater than ±12.0V with respect to GND. (HI-3182, 3184 & 3187 only) Note 2.

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

HI-3182, HI-3183, HI-3184, HI-3185, HI-3186, HI-3187, HI-3188

DC ELECTRICAL CHARACTERISTICS

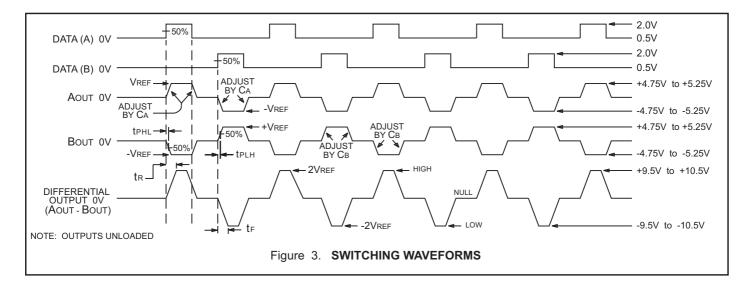
+V = +15V, -V = -15V, $V_1 = V_{REF} = +5.0V$, TA = Operating Temperature Range (unless otherwise specified).

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS				
Supply Current +V (Operating)	ICCOP (+V)	No Load (0 - 100KBPS)			+16	mA				
Supply Current -V (Operating)	ICCOP (-V)	No Load (0 - 100KBPS)	-16			mA				
Supply Current V1 (Operating)	ICCOP (V1)	No Load (0 - 100KBPS)			500	μA				
Reference Pin Current VREF (Operating)	ICCOP (VREF)	No Load, VREF = 5V (0 - 100KBPS)	-1.0	-0.4	-0.15	mA				
Supply Current +V (During Short Circuit Test)	ISC (+V)	Short to Ground (See Note: 1)			150	mA				
Supply Current -V (During Short Circuit Test)	Isc (-V)	Short to Ground (See Note: 1)	-150			mA				
Output Short Circuit Current (Output High)	loнsc	Short to Ground VMIN=0 (See Note: 2)			-80	mA				
Output Short Circuit Current (Output Low)	Iolsc	Short to Ground VMIN=0 (See Note: 2)	+80			mA				
Input Current (Input High)	Іін				1.0	μA				
Input Current (Input Low)	lı∟		-1.0			μA				
Input Voltage High	Viн		2.0			V				
Input Voltage Low	VIL				0.5	V				
Output Voltage High (Output to Ground)	Vон	No Load (0 -100KBPS)	+VREF 25		+VREF +.25	V				
Output Voltage Low (Output to Ground)	Vol	No Load (0 -100KBPS)	-Vref 25		-VREF +.25	V				
Output Voltage Null	VNULL	No Load (0-100KBPS)	-250		+250	mV				
Input Capacitance	CIN	See Note 1		15		pF				
	Note 1. Not tested, but characterized at initial device design and after major process and/or design change which affects this parameter. Note 2. Interchangeability of force and sense is acceptable.									

AC ELECTRICAL CHARACTERISTICS

+V = +15V, -V = -15V, V1 = VREF = +5.0V, TA = Operating Temperature Range (unless otherwise specified).

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS
Rise Time (AOUT, BOUT)	tR	CA = CB = 75pF See Figure 3.	1.0		2.0	μs
Fall Time (AOUT, BOUT)	tF	CA = CB = 75pF See Figure 3.	1.0		2.0	μs
Propagtion Delay Input to Output	t PLH	CA = CB = 75pF See Figure 3.			3.0	μs
Propagtion Delay Input to Output	t PHL	CA = CB = 75pF See Figure 3.			3.0	μs



HI-318X PACKAGE THERMAL CHARACTERISTICS

PACKAGE STYLE ¹	HEAT SINK	ØJA	SUPPLY CURRENT ²	JUNCTION TEMPERATURE, Tj			
PACKAGE STILE	HEAT SINK	(°C/W)	SUPPLY CORRENT	TA = 25°C	TA = 85°C	TA = 125°C	
14-pin Thermally Enhanced Plastic	Unsoldered	82	20 mA	57°C	117°C	157°C	
SOIC (ESOIC)	Soldered	65	20 mA	51°C	111°C	151°C	
14-pin Thermally Enhanced Plastic	Unsoldered	51	20 mA	45°C	105°C	145°C	
SOIC (ESOIC)	Soldered	28	20 mA	36°C	96°C	136°C	
28-pin Plastic PLCC	N/A	70	25 mA	56°C	110°C	150°C	

MAXIMUM ARINC LOAD ^{3, 6, 7}

AOUT and BOUT Shorted to Ground ^{3, 4, 5, 6, 7}

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PACKAGE STYLE ¹	HEAT SINK	ØJA	SUPPLY CURRENT ²	JUNCTION TEMPERATURE, Tj			
		(°C/W)	SOTTET CORRENT	TA = 25°C	TA = 85°C	TA = 125°C	
14-pin Thermally Enhanced Plastic	Unsoldered	82	36 mA	57°C	147°C	187°C	
SOIC (ESOIC)	Soldered	65	36 mA	78°C	138°C	178°C	
14-pin Thermally Enhanced Plastic	Unsoldered	51	40 mA	64°C	124°C	164°C	
SOIC (ESOIC)	Soldered	28	40 mA	53°C	113°C	153°C	
28-pin Plastic PLCC	N/A	70	63 mA	100°C	150°C	182°C	

Notes:

- 1. All data taken in still air on devices soldered to a single layer copper PCB (3" X 4.5" X .062").
- 2. At 100% duty cycle, 15V power supplies. For 12V power supplies multiply all tabulated values by 0.8.
- 3. High Speed: Data Rate = 100 Kbps, Load: R = 400 Ohms, C = 10 nF. Data not presented for C = 30 nF as this is considered unrealistic for high speed operation.
- 4. Similar results would be obtained with AOUT shorted to BOUT.
- 5. For applications requiring survival with continuous short circuit, operation above Tj = 175°C is not recommended.
- 6. Data will vary depending on air flow and the method of heat sinking employed.
- 7. Current values listed are for each of the +V and -V supplies.

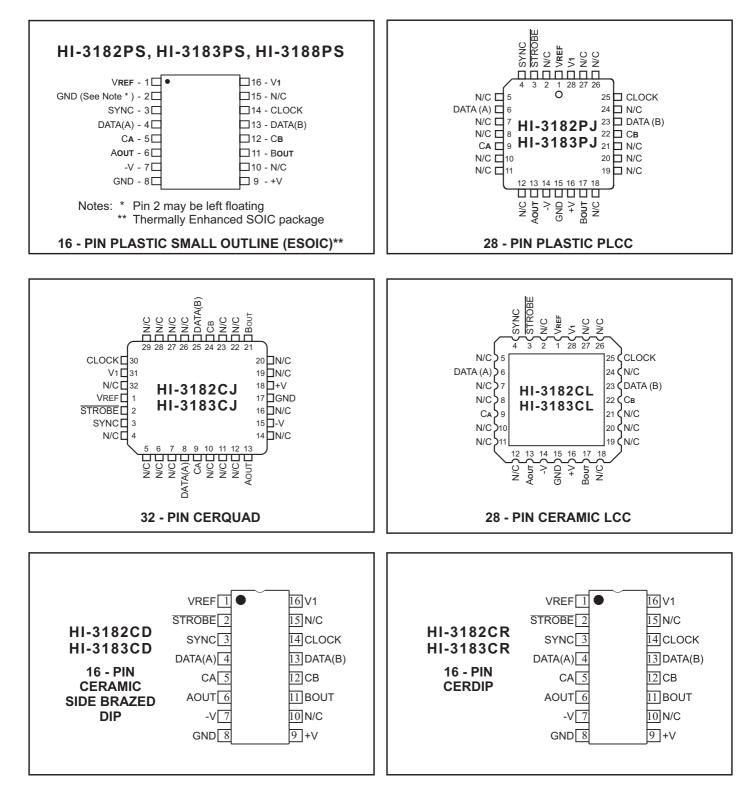
HEAT SINK - ESOIC PACKAGES

Both the 14-pin and 16-pin thermally enhanced SOIC dissipation. The heat sink is packages are used for HI-318X products. These ESOIC chip and can be soldered to packages include a metal heat sink located on the bottom surface of the device. This heat sink should be soldered to the heat sink to this power plated own to the printed circuit board for optimum thermal coupling noise into the circuit.

dissipation. The heat sink is electrically isolated from the chip and can be soldered to any ground or power plane. However, since the chip's substrate is at +V, connecting the heat sink to this power plane is recommended to avoid coupling noise into the circuit.

HI-3182, HI-3183, HI-3184, HI-3185, HI-3186, HI-3187, HI-3188

ADDITIONAL PIN CONFIGURATIONS (See page 1 for 14-Pin Small Outline SOIC)



ORDERING INFORMATION

HI - <u>318x x x - xx</u> (Ceramic)

	PART NUMBER	TEMPERATURI RANGE	E	FLOW	BURN	l				
	I	-40°C TO +85	°C	I	NO					
	Т	-55°C TO +12	5°C	Т	NO					
	М	-55°C TO +12	5°C	М	YES					
	PART NUMBER	PACKAGE DESCRIPTION						LEAD FINISH (1)		
	CD	16 PIN CERAMI	IC SIDI	E BRAZE	D DIP			Gold ('M' flow: solder)		
	CJ	32 PIN J-LEAD	CERQ	UAD (no	available	with	'M' flow)	Solder		
	CL	28 PIN CERAMI	IC LEA	DLESS	CHIP CAR	RIEF	R (LCC)	Gold ('M' flow: solder)		
	CR	16 PIN CERDIP	(not a	vailable v	rith 'M' flow)			Solder		
	PART	OUTPUT SERIES		6						
	NUMBER	RESISTANCE	FU	SE						
	3182	37.5 Ohms	Y	ES						
	3183	13 Ohms	N	0						

HI - <u>318xxx x x</u> (Plastic)

PART NUMBER	LEAD FINISH					
Blank	Tin / Lead (Sn / Pb) Solder					
F	100% Matte Tin (Pb-free, RoHS compliant)					
 PART NUMBER	TEMPERATURE RANGE	FLOW	BURN IN			
I	-40°C TO +85°C	I	NO			
Т	-55°C TO +125°C	Т	NO			
M (2)	-55°C TO +125°C	М	YES			

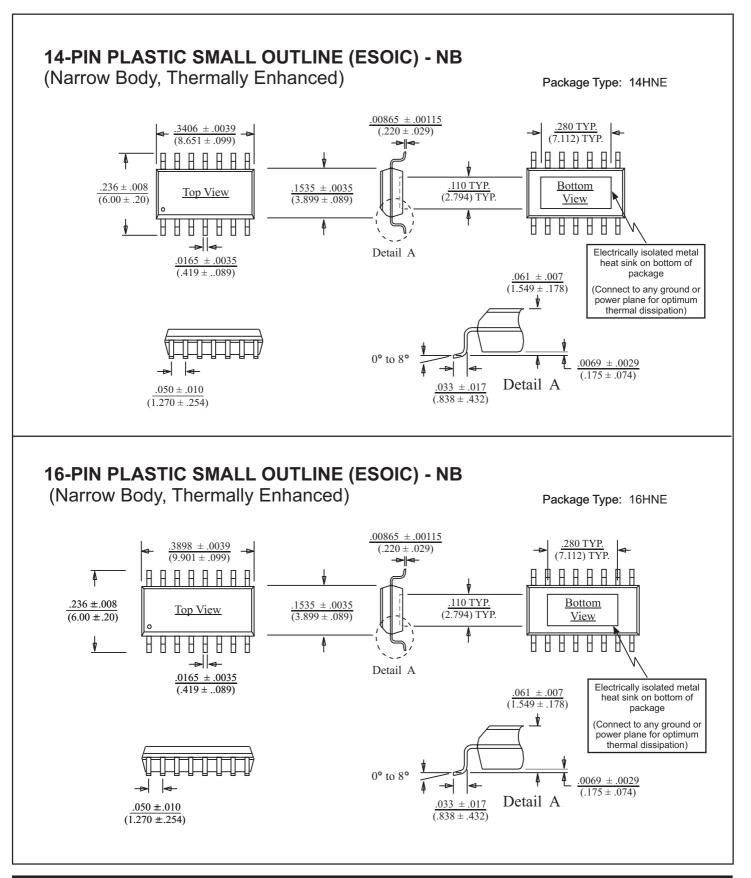
PART			SERIES
NUMBER	DESCRIPTION	RESISTANCE	FUSE
3182PJ	28 PIN PLASTIC J-LEAD PLCC	37.5 Ohms	YES
3182PS	16 PIN PLASTIC SMALL OUTLINE - WB (ESOIC)	37.5 Ohms	YES
3183PJ	28 PIN PLASTIC J-LEAD PLCC	13 Ohms	NO
3183PS	16 PIN PLASTIC SMALL OUTLINE - WB (ESOIC)	13 Ohms	NO
3184PS	14 PIN PLASTIC SMALL OUTLINE - NB (ESOIC)	37.5 Ohms	YES
3185PS	14 PIN PLASTIC SMALL OUTLINE - NB (ESOIC)	37.5 Ohms	NO
3186PS	14 PIN PLASTIC SMALL OUTLINE - NB (ESOIC)	13 Ohms	NO
3187PS	14 PIN PLASTIC SMALL OUTLINE - NB (ESOIC)	13 Ohms	YES
3188PS	16 PIN PLASTIC SMALL OUTLINE - WB (ESOIC)	13 Ohms	NO

Legend: ESOIC - Thermally Enhanced Small Outline Package (SOIC w/built-in heat sink) NB - Narrow Body WB - Wide Body

- Gold terminal finish is Pb-Free, RoHS compliant.
 Only available with '3182PJ'.

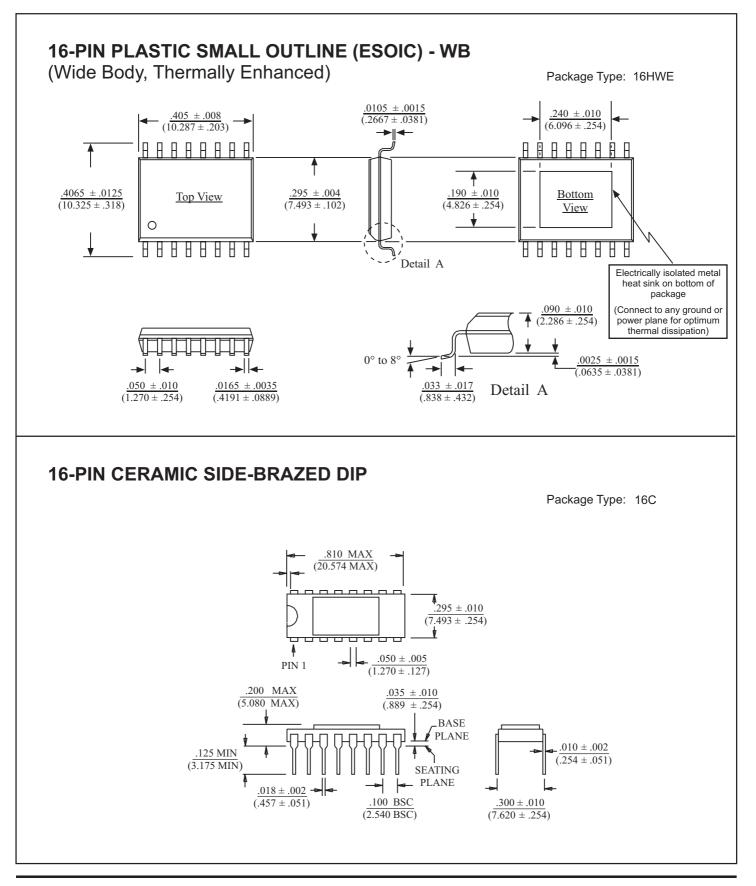


inches (millimeters)



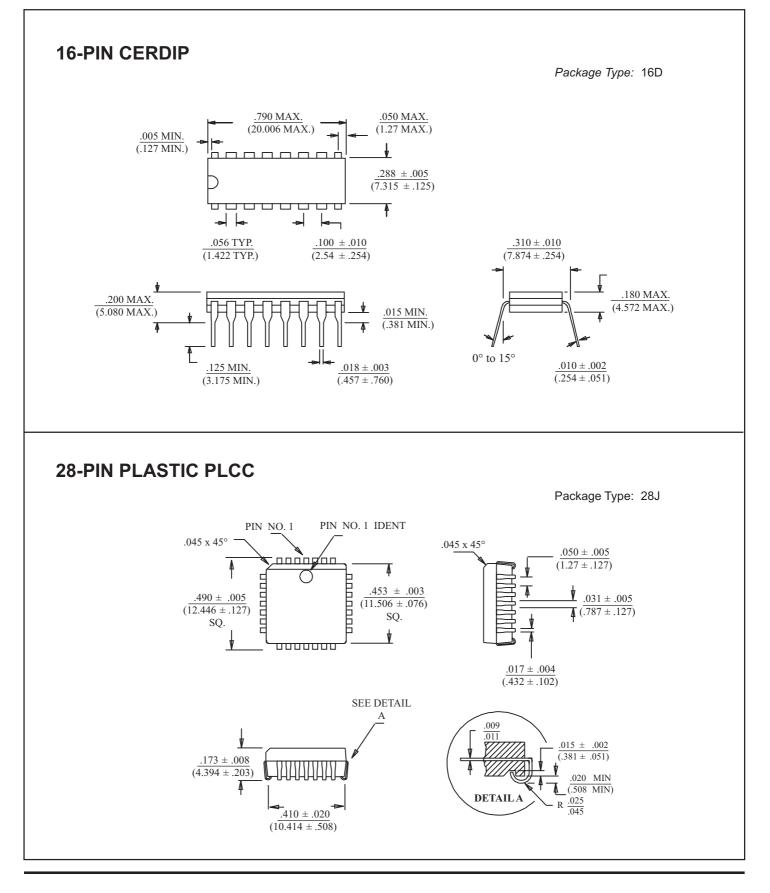


inches (millimeters)





inches (millimeters)





inches (millimeters)

